

# On The PoC Inductor Selection

July 28, 2025

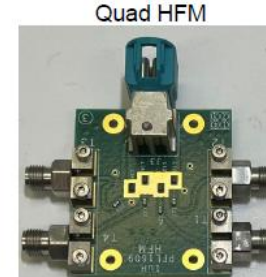
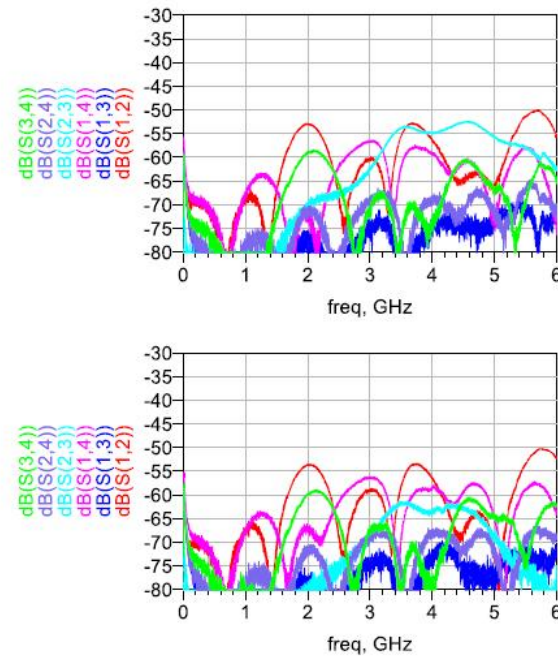
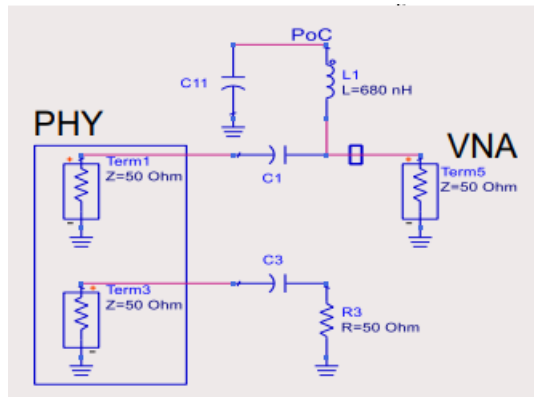
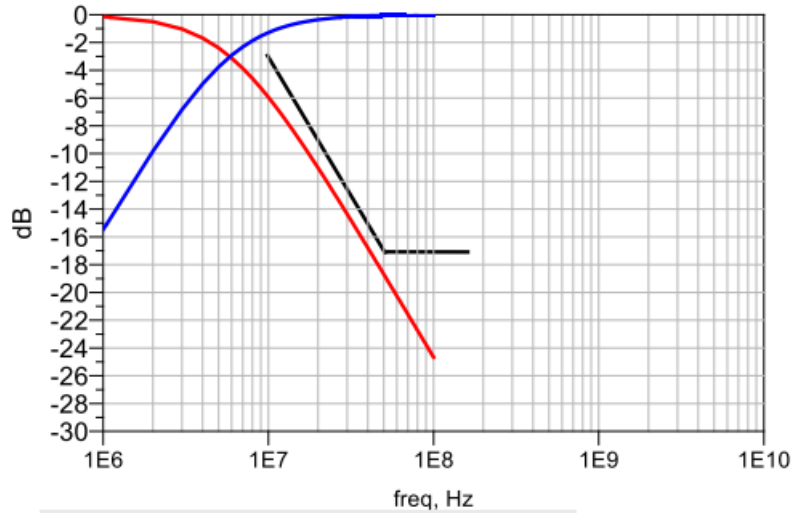
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# Foreword

- PoC inductor choices and effect was discussed earlier<sup>1</sup> with the intention of reducing complexity and improve power efficiency.
- It was shown that with a proper MDI RL specification for 802.3dm, the inductor values down 1 $\mu$ H (typical) is allowed.
- The goal of PoC inductor optimization is not only to achieve a single inductor PoC solution, but also to optimize power loss, board area, relative cost, among others.
- This document shows the PoC inductors with smaller inductance provide favorite performance.

1- [https://www.ieee802.org/3/dm/public/0924/Chini\\_Tazebay\\_3dm\\_01a\\_0924.pdf](https://www.ieee802.org/3/dm/public/0924/Chini_Tazebay_3dm_01a_0924.pdf)

# 1uH PoC inductor Example<sup>1</sup>

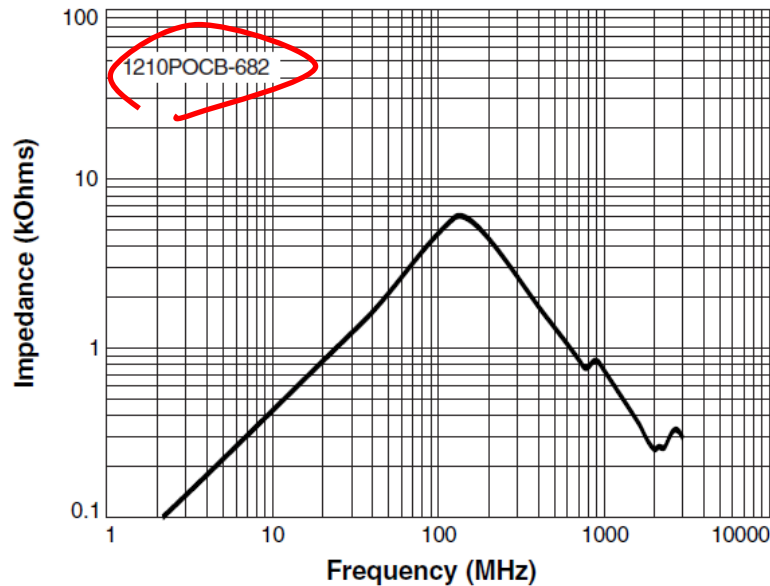


PFL1609 has a physical size of 1.6mm by 0.9mm

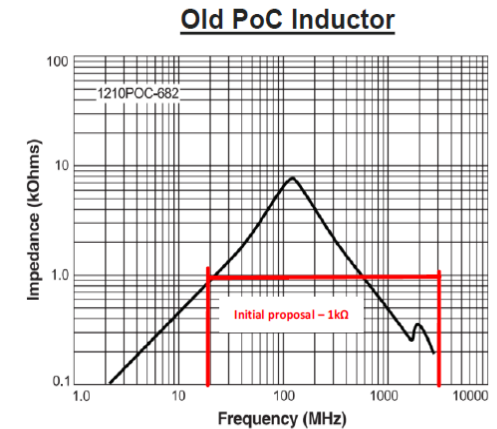
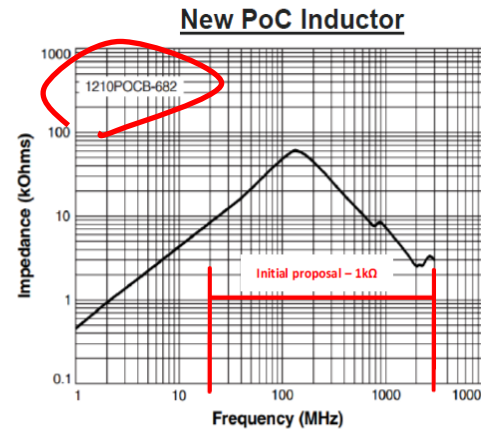
- It was shown earlier<sup>1</sup> that a PoC inductor of **1μH**, e.g. PFL1609 may be used to meet MDI RL and with a good XTALK performance in a quad implementation and with a small board size

1- [https://www.ieee802.org/3/dm/public/0924/Chini\\_Tazebay\\_3dm\\_01a\\_0924.pdf](https://www.ieee802.org/3/dm/public/0924/Chini_Tazebay_3dm_01a_0924.pdf)

# New 6.8uH PoC Inductor!



- Older PoC inductors have issues meeting the broadband noise rejection required for 802.3dm
- New PoC inductors are able cover broadband noise rejection required with broadband impedance response



Referenced: <https://www.coilcraft.com/getmedia/9804936a-6bb5-49a8-bcd2-09eba1192490/1210pocb.pdf>

Referenced: <https://www.coilcraft.com/getmedia/5e8de018-68c5-4442-84ce-d5212c44660c/1210poc.pdf>

IEEE 802.3dm Task Force

- The so called “New PoC inductor” plot<sup>1</sup> is easily calculated from low frequency impedance to be 68.2μH and **not** 6.8μH! (a typo?)
- The referenced link shows the plot for 1210POCB-682 which is a 6.82μH and not as shown in the presentation<sup>2</sup>. With that, the stated proposal of staying above 1kOhm over whole bandwidth is not achieved.

2- [https://www.ieee802.org/3/dm/public/0125/Houck\\_3dm\\_02\\_0121\\_5.pdf](https://www.ieee802.org/3/dm/public/0125/Houck_3dm_02_0121_5.pdf)

# Mystery PoC Inductor for FDD<sup>3</sup>

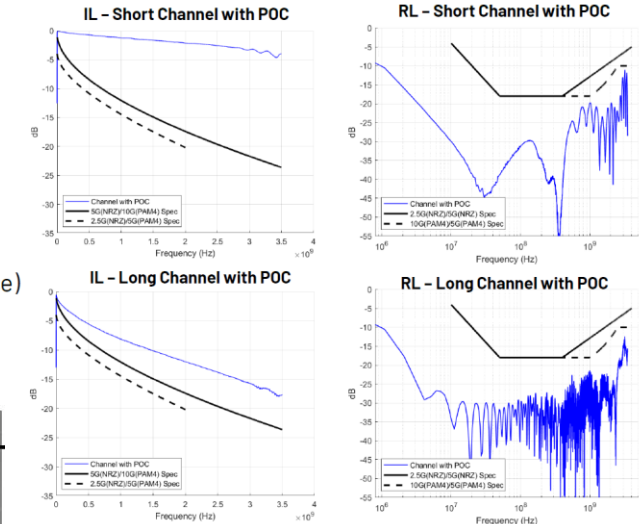
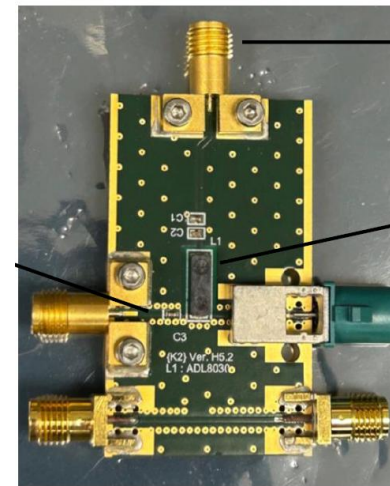
- The Return Loss plots for FDD<sup>3</sup>, clearly show the proposed PoC inductor has inductance of greater than 10 $\mu$ H.
- The part number was not disclosed!
- The self resonance frequency of the inductor when installed on the board is seen to be about 30MHz.
- DCR of the inductor and power rating is not disclosed.
- The size of the inductor is not provided but judging by the connector size on the board, It should be about 8mm by 2mm.

## Mystery Revealed: Single Inductor POC with



- Single inductor POC solution measured at 600mA load current:

- Short channel – 0.5m RTK031-type cable + 2xPOC at 105C (RL worst case)
- Long channel – 13.5m RTK031 with 2xPOC at 105C (IL worst case)



# Important Parameters for PoC Inductor Selection

- The MDI RL previously adopted for 802.3dm, allows inductors with typical values down to **1μH** to be used.
- 802.3dm contributions on FDD<sup>1</sup> and ACT have suggested larger inductor values and sizes.
- While single inductor solution has been a goal for all the proposed signaling approaches, there are other Important parameters for optimizing the PoC inductors.
  - **SRF:** Typically, PoC Inductors with higher SRF show better high frequency performance.
  - **DCR:** Lower DCR means lower power loss and less heat dissipation.
  - **Rated Current:** The working current with no significant self heat and saturation.
  - **Relative cost:** Ability to operate over a smaller inductor is beneficial for cost optimization as well.
  - **Width** (pad size): Smaller pad size on the board is preferred to reduce parasitic capacitance.
  - **Load variation noise:** Lower the inductance, lower is the transient noises generated by variation in the load (  $L \cdot di/dt$  )

1- [https://www.ieee802.org/3/dm/public/0325/████████FDD\\_PHY\\_Simulation\\_Results\\_and\\_PHY\\_Complexity\\_rev1p0.pdf](https://www.ieee802.org/3/dm/public/0325/████████FDD_PHY_Simulation_Results_and_PHY_Complexity_rev1p0.pdf)

## Example Component Size, Various Inductances

| Part number <sup>1</sup> | Inductance <sup>2</sup><br>±20% (μH) | DCR (mOhms) <sup>3</sup> |      | SRF typ <sup>4</sup><br>(MHz) | Isat (mA) <sup>5</sup> |          |          | Irms (mA) <sup>6</sup> |           |
|--------------------------|--------------------------------------|--------------------------|------|-------------------------------|------------------------|----------|----------|------------------------|-----------|
|                          |                                      | typ                      | max  |                               | 10% drop               | 20% drop | 30% drop | 20°C rise              | 40°C rise |
| PFL3215-681ME_           | 0.68                                 | 28                       | 33   | 450                           | 2100                   | 2500     | 2700     | 1500                   | 2100      |
| PFL3215-102ME_           | 1.0                                  | 30                       | 38   | 375                           | 1800                   | 2100     | 2300     | 1400                   | 1900      |
| PFL3215-222ME_           | 2.2                                  | 114                      | 130  | 250                           | 950                    | 1200     | 1400     | 1100                   | 1400      |
| PFL3215-332ME_           | 3.3                                  | 175                      | 195  | 190                           | 730                    | 920      | 1100     | 820                    | 1100      |
| PFL3215-472ME_           | 4.7                                  | 332                      | 372  | 170                           | 640                    | 810      | 900      | 520                    | 720       |
| PFL3215-682ME_           | 6.8                                  | 640                      | 720  | 155                           | 600                    | 700      | 750      | 370                    | 500       |
| PFL3215-103ME_           | 10                                   | 1290                     | 1340 | 125                           | 500                    | 550      | 600      | 300                    | 390       |
| PFL3215-153ME_           | 15                                   | 1800                     | 2100 | 105                           | 350                    | 420      | 440      | 240                    | 320       |
| PFL3215-333ME_           | 33                                   | 1700                     | 1920 | 13.5                          | 290                    | 340      | 360      | 270                    | 360       |

- The table above shows a range of power inductors with the same physical size of 3.2mm by 1.5mm
- Comparing DCR, SRF, and current level, it is seen that low inductance components have better DCR, SRF and current handling.

# 1μH versus 6.8μH PoC Inductor Examples

- **PFL2015-102 (a good choice for TDD)**
  - AEC-Q200, -40C to +125C
  - Size: 2.2 x **1.27** x 1.5
  - Inductance: 1μH
  - Max DCR (@25C): 130mΩ
  - SRF: 450MHz
  - Current (10% saturation and 20C rise): 900mA

- **1210POCB-682 (suggested for ACT<sup>2</sup>)**
  - AEC-Q200, -40C to +125C
  - Size: 3.3 x **2.67** x 2.0
  - Inductance: 6.8μH
  - Max DCR (@25C): 210mΩ
  - SRF: 120MHz
  - Current (30% saturation and 15C rise at 125C): 620mA

| Current Level | TDD<br>PFL2510-102 | ACT<br>1210POCB-682 |
|---------------|--------------------|---------------------|
| 300mA         | 15mW               | 25mW                |
| 600mA         | 61mW               | 98mW                |

30% rise in DCR assumed with temperature

- The POC inductor suggested for ACT has
  - Larger pad size (2.67mm vs 1.27mm)
  - Lower current rating
  - ~66% Higher DCR (power loss)
  - ~40% Higher cost (<https://www.coilcraft.com>)

2- [https://www.ieee802.org/3/dm/public/0125/Houck\\_3dm\\_02\\_0121\\_5.pdf](https://www.ieee802.org/3/dm/public/0125/Houck_3dm_02_0121_5.pdf)

## Summary and Conclusions

- The particular PoC inductors suggested for FDD\* and ACT\*\* have larger inductance than 1 $\mu$ H PoC inductor suggested for TDD.
- While single inductor PoC solution is mentioned for ACT, some other aspects of PoC inductor are not optimized.
- For a given physical size, 1 $\mu$ H inductor provides great advantages for DCR, SRF and current rating.
- There are many good choices available for 1 $\mu$ H PoC solution. An example PoC inductor is shown to have, lower size, higher current rating, lower power loss and lower cost when compared to 1210POCB-682 suggested for ACT.
- For TDD, there are many good 1 $\mu$ H inductors available that meet the MDI RL and provide more efficient solutions for PoC.

\* [https://www.ieee802.org/3/dm/public/0325/0325\\_FDD\\_PHY\\_Simulation\\_Results\\_and\\_PHY\\_Complexity\\_rev1p0.pdf](https://www.ieee802.org/3/dm/public/0325/0325_FDD_PHY_Simulation_Results_and_PHY_Complexity_rev1p0.pdf)

\*\* [https://www.ieee802.org/3/dm/public/0125/Houck\\_3dm\\_02\\_0121\\_5.pdf](https://www.ieee802.org/3/dm/public/0125/Houck_3dm_02_0121_5.pdf)

Thank you  
Questions?